

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group Art Unit: tba  
Examiner: tba

In Re PATENT APPLICATION OF

Applicant(s): Alexandre ELLISON et al.

Appl. No.: 10/526,259

Filing Date: February 28, 2005

For: LIGHTLY DOPED SILICON CARBIDE WAFER  
AND USE THEREOF IN HIGH POWER DEVICES

Atty. Dkt.: 35947-213490

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)  
) INFORMATION  
) DISCLOSURE  
) STATEMENT  
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) 26694  
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October 13, 2005

Commissioner for Patents  
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Sir:

This is an Information Disclosure Statement submitted under 37 C.F.R. § 1.97 within the time specified under 37 C.F.R. § 1.97(b).

Enclosed is a PTO-1449, and copies of references cited therein.

This Information Disclosure Statement is being filed before the mailing date of a first Office Action on the merits.

Respectfully submitted,



Eric J. Franklin, Registration No. 37,134

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
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PTO/SB/08A (08-00)

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# INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

## Complete if Known

Application Number	10/526,059
Filing Date	February 28, 2005
First Named Inventor	Alexandre ELLISON et al.
Group Art Unit	tba
Examiner Name	tba
Attorney Docket Number	35947-213490

Sheet 1 of 1

## U.S. PATENT DOCUMENTS

Examiner Initials *	Cite No. <sup>1</sup>	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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## OTHER PRIOR ART -- NON PATENT LITERATURE DOCUMENTS

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/ntg/	1	J.R. JENNY, M. SKOWRONSKI, W.C. MITCHEL, H.M. HOBGOOD, R.C. GLASS, G. AUGUSTINE and R.H. HOPKINS; Optical and electrical characterization of boron impurities in silicon carbide grown by physical vapor transport; J. Appl. Phys. 79 (5), March 1996; pps. 2326-2331.	
/ntg/	2	M. TRIVEDI, S. PENDHARKAR and K. SHENAI; High Temperature Performance Limits of IGBT Modules; 1998 IEEE; pps. 977-981.	
/ntg/	3	AKIRA ITOH and HIROYUKI MATSUNAMI; Single Crystal Growth of SiC and Electronic Devices; Critical Reviews in Solid State and Materials Sciences; 1997; 22(2); pps. 111-197; CRC Press LLC.	

Examiner Signature	/Nicole T. Gugliotta/	Date Considered	10/24/2007
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